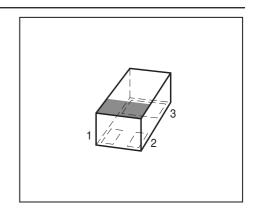


NPN Bipolar RF Transistor

- For low noise, high-gain amplifiers up to 2 GHz
- For linear broadband amplifiers
- f_T = 8 GHz, NF_{min} = 1 dB at 900 MHz
- Pb-free (RoHS compliant) package
- Qualification report according to AEC-Q101 available





ESD (Electrostatic discharge) sensitive device, observe handling precaution!

| Туре | Marking | Pin Configuration | | | Package | |
|----------|---------|-------------------|-------|-------|----------|--|
| BFR193L3 | RC | 1 = B | 2 = E | 3 = C | TSLP-3-1 | |

Maximum Ratings at T_A = 25 °C, unless otherwise specified

| Parameter | Symbol | Value | Unit |
|---------------------------------------|--------------------|---------|------|
| Collector-emitter voltage | $V_{\sf CEO}$ | 12 | V |
| Collector-emitter voltage | V_{CES} | 20 | |
| Collector-base voltage | V_{CBO} | 20 | |
| Emitter-base voltage | V_{EBO} | 2 | |
| Collector current | I _C | 80 | mA |
| Base current | I _B | 10 | |
| Total power dissipation ¹⁾ | P _{tot} | 580 | mW |
| <i>T</i> _S ≤ 89°C | | | |
| Junction temperature | TJ | 150 | °C |
| Storage temperature | T_{Stg} | -55 150 | |

Thermal Resistance

| Parameter | Symbol | Value | Unit |
|--|-------------------|-------|------|
| Junction - soldering point ²⁾ | R _{thJS} | 105 | K/W |

¹T_S is measured on the collector lead at the soldering point to the pcb

 $^{^2}$ For calculation of R_{thJA} please refer to Application Note AN077 (Thermal Resistance Calculation)



Electrical Characteristics at $T_A = 25$ °C, unless otherwise specified

| Parameter | Symbol | l Values | | | Unit |
|---|----------------------|----------|------|------|------|
| | | min. | typ. | max. | |
| DC Characteristics | | | | | |
| Collector-emitter breakdown voltage | V _{(BR)CEO} | 12 | - | - | V |
| $I_{\rm C}$ = 1 mA, $I_{\rm B}$ = 0 | | | | | |
| Collector-emitter cutoff current | I _{CES} | - | - | 100 | μA |
| $V_{CE} = 20 \text{ V}, V_{BE} = 0$ | | | | | |
| Collector-base cutoff current | I _{CBO} | - | - | 100 | nA |
| $V_{\rm CB} = 10 \text{ V}, I_{\rm E} = 0$ | | | | | |
| Emitter-base cutoff current | I _{EBO} | - | - | 1 | μA |
| $V_{\rm EB} = 1 \text{ V}, I_{\rm C} = 0$ | | | | | |
| DC current gain | h _{FE} | 70 | 100 | 140 | - |
| $I_{\rm C}$ = 30 mA, $V_{\rm CE}$ = 8 V, pulse measured | | | | | |



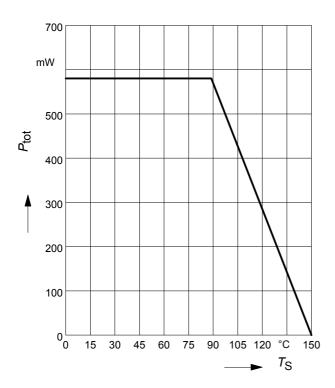
Electrical Characteristics at T_{Δ} = 25°C, unless otherwise specified

| Parameter | Symbol | Values | | | Unit |
|--|---------------------------------|--------|------|--------|------|
| | | min. | typ. | max. | |
| AC Characteristics (verified by random samp | oling) | | | · • | |
| Transition frequency | f _T | 6 | 8 | - | GHz |
| $I_{\rm C}$ = 50 mA, $V_{\rm CE}$ = 8 V, f = 500 MHz | | | | | |
| Collector-base capacitance | C _{cb} | - | 0.63 | 0.9 | pF |
| $V_{\text{CB}} = 10 \text{ V}, f = 1 \text{ MHz}, V_{\text{BE}} = 0$, | | | | | |
| emitter grounded | | | | | |
| Collector emitter capacitance | C _{ce} | - | 0.22 | - | |
| $V_{CE} = 10 \text{ V}, f = 1 \text{ MHz}, V_{BE} = 0$, | | | | | |
| base grounded | | | | | |
| Emitter-base capacitance | C _{eb} | - | 2.25 | - | |
| $V_{\text{EB}} = 0.5 \text{ V}, f = 1 \text{ MHz}, V_{\text{CB}} = 0$, | | | | | |
| collector grounded | | | | | |
| Minimum noise figure | <i>NF</i> _{min} | | | | dB |
| $I_{\rm C}$ = 10 mA, $V_{\rm CE}$ = 8 V, $Z_{\rm S}$ = $Z_{\rm Sopt}$, | | | | | |
| f = 900 MHz | | - | 1 | - | |
| $I_{\rm C}$ = 10 mA, $V_{\rm CE}$ = 8 V, $Z_{\rm S}$ = $Z_{\rm Sopt}$, | | | | | |
| f = 1.8 GHz | | - | 1.6 | - | |
| Power gain, maximum available ¹⁾ | G _{ma} | | | | |
| $I_{\rm C}$ = 30 mA, $V_{\rm CE}$ = 8 V, $Z_{\rm S}$ = $Z_{\rm Sopt}$, | | | | | |
| $Z_{L} = Z_{Lopt}$, $f = 900 \text{ MHz}$ | | - | 19 | - | |
| $I_{\rm C}$ = 30 mA, $V_{\rm CE}$ = 8 V, $Z_{\rm S}$ = $Z_{\rm Sopt}$, | | | | | |
| $Z_{L} = Z_{Lopt}$, $f = 1.8 \text{ GHz}$ | | - | 12.5 | - | |
| Transducer gain | S _{21e} ² | | | | dB |
| $I_{\rm C}$ = 30 mA, $V_{\rm CE}$ = 8 V, $Z_{\rm S}$ = $Z_{\rm L}$ = 50 Ω , | | | | | |
| f = 900 MHz | | - | 14.5 | - | |
| $I_{\rm C}$ = 30 mA, $V_{\rm CE}$ = 8 V, $Z_{\rm S}$ = $Z_{\rm L}$ = 50 Ω , | | | | | |
| f = 1.8 GHz | | - | 9 | - | |

 $^{{}^{1}}G_{\text{ma}} = |S_{21} / S_{12}| (k-(k^2-1)^{1/2})$

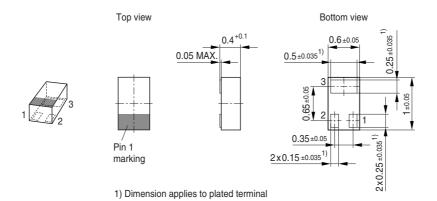


Total power dissipation $P_{tot} = f(T_S)$



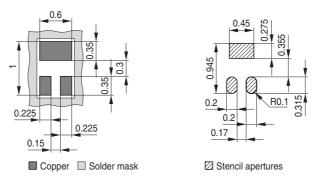


Package Outline

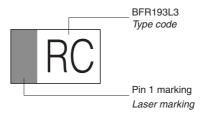


Foot Print

For board assembly information please refer to Infineon website "Packages"

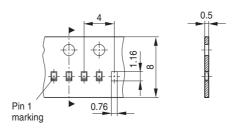


Marking Layout (Example)



Standard Packing

Reel ø180 mm = 15.000 Pieces/Reel





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